
HD74AC245/HD74ACT245

Octal Bi-directional Transceiver with 3-State Input/Output

HITACHI

ADE-205-384 (Z)
1st. Edition
Sep. 2000

Description

The HD74AC245/HD74ACT245 contains eight non-inverting bidirectional buffers with 3-state outputs and is intended for bus-oriented applications. Current sinking capability is 24 mA at both the A and B ports. The Transmit/Receive ($T/\overline{R}$) input determines the direction of data flow through the bidirectional transceiver. Transmit (active-High) enables data from A ports to B ports; Receive (active-Low) enables data from B ports to A ports. The Output Enable input, when High, disables, both A and B ports by placing them in a High Z condition.

Features

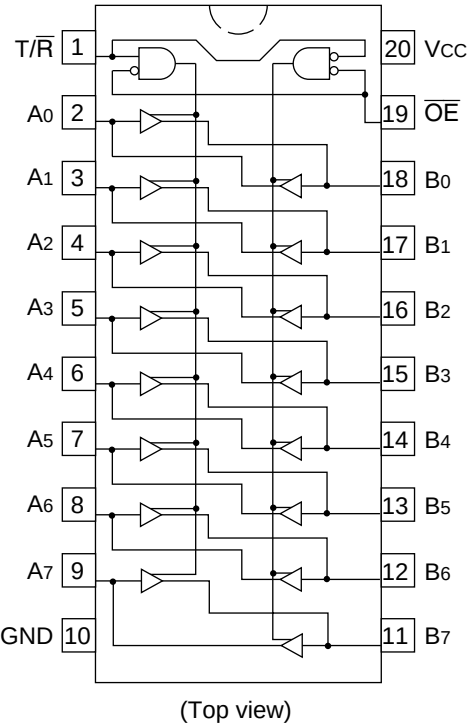
- Noninverting Buffers
- Bi-directional Data Path
- A and B Outputs Source/Sink 24 mA
- HD74ACT245 has TTL-Compatible Inputs

Pin Names

$\overline{OE}$	Output Enable Input
$T/\overline{R}$	Transmit/Receive Input
A_0 to A_7	Side A 3-State Inputs or 3-State Outputs
B_0 to B_7	Side B 3-State Inputs or 3-State Outputs

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Pin Arrangement



Truth Tables

Inputs		
OE	T/R	Outputs
L	L	Bus B Data to Bus A
L	H	Bus A Data to Bus B
H	X	High Z State

H : High Voltage Level
L : Low Voltage Level
X : Immaterial

DC Characteristics (unless otherwise specified)

Item	Symbol	Max	Unit	Condition
Maximum quiescent supply current	I_{CC}	80	μA	$V_{IN} = V_{CC}$ or ground, $V_{CC} = 5.5 V$, $T_a = \text{Worst case}$
Maximum quiescent supply current	I_{CC}	8.0	μA	$V_{IN} = V_{CC}$ or ground, $V_{CC} = 5.5 V$, $T_a = 25^\circ C$
Maximum additional I_{CC}/input (HD74ACT245)	I_{CCT}	1.5	mA	$V_{IN} = V_{CC} - 2.1 V$, $V_{CC} = 5.5 V$, $T_a = \text{Worst case}$

AC Characteristics: HD74AC245

Item	Symbol	$V_{CC} (V)^{*1}$	$T_a = +25^\circ C$ $C_L = 50 pF$			$T_a = -40^\circ C \text{ to } +85^\circ C$ $C_L = 50 pF$		Unit
			Min	Typ	Max	Min	Max	
Propagation delay	t_{PLH}	3.3	1.0	5.0	8.5	1.0	9.0	ns
Data to output		5.0	1.0	3.5	6.5	1.0	7.0	
Propagation delay	t_{PHL}	3.3	1.0	5.0	8.5	1.0	9.0	ns
Data to output		5.0	1.0	3.5	6.0	1.0	7.0	
Output enable time	t_{ZH}	3.3	1.0	7.0	11.5	1.0	12.5	ns
		5.0	1.0	5.0	8.5	1.0	9.0	
Output enable time	t_{ZL}	3.3	1.0	7.5	12.0	1.0	13.5	ns
		5.0	1.0	5.5	9.0	1.0	9.5	
Output disable time	t_{HZ}	3.3	1.0	6.5	12.0	1.0	12.5	ns
		5.0	1.0	5.5	9.0	1.0	10.0	
Output disable time	t_{LZ}	3.3	1.0	7.0	11.5	1.0	13.0	ns
		5.0	1.0	5.5	9.0	1.0	10.0	

Note: 1. Voltage Range 3.3 is $3.3 V \pm 0.3 V$
Voltage Range 5.0 is $5.0 V \pm 0.5 V$

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AC Characteristics: HD74ACT245

Item	Symbol	V _{CC} (V)* ¹	Ta = +25°C C _L = 50 pF			Ta = −40°C to +85°C C _L = 50 pF		Unit
			Min	Typ	Max	Min	Max	
Propagation delay Data to output	t _{PLH}	5.0	1.0	4.0	7.5	1.0	8.0	ns
Propagation delay Data to output	t _{PHL}	5.0	1.0	4.0	8.0	1.0	9.0	ns
Output enable time	t _{ZH}	5.0	1.0	5.0	10.0	1.0	11.0	ns
Output enable time	t _{ZL}	5.0	1.0	5.5	10.0	1.0	12.0	ns
Output disable time	t _{HZ}	5.0	1.0	5.5	10.0	1.0	11.0	ns
Output disable time	t _{LZ}	5.0	1.0	5.0	10.0	1.0	11.0	ns

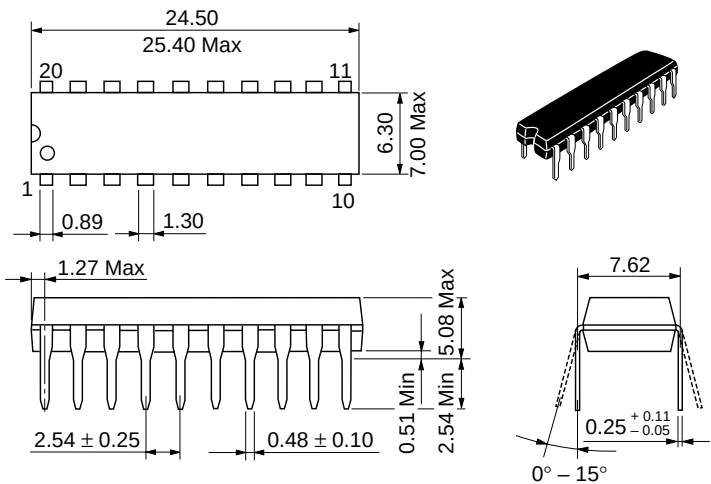
Note: 1. Voltage Range 5.0 is 5.0 V ± 0.5 V

Capacitance

Item	Symbol	Typ	Unit	Condition
Input capacitance	C _{IN}	4.5	pF	V _{CC} = 5.5 V
Input/output capacitance	C _{I/O}	15.0	pF	V _{CC} = 5.5 V
Power dissipation capacitance	C _{PD}	45.0	pF	V _{CC} = 5.0 V

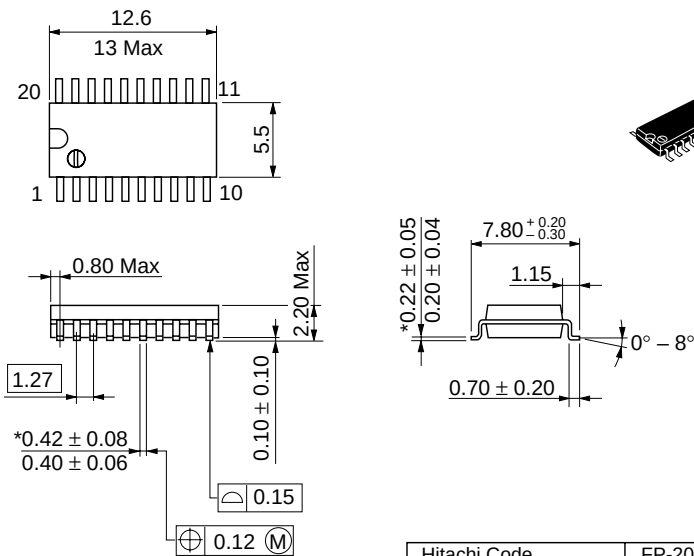
Package Dimensions

Unit: mm



Hitachi Code	DP-20N
JEDEC	—
EIAJ	Conforms
Mass (reference value)	1.26 g

Unit: mm

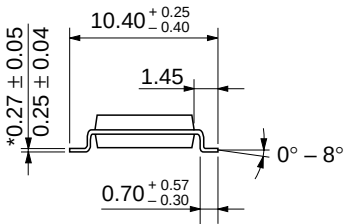
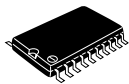
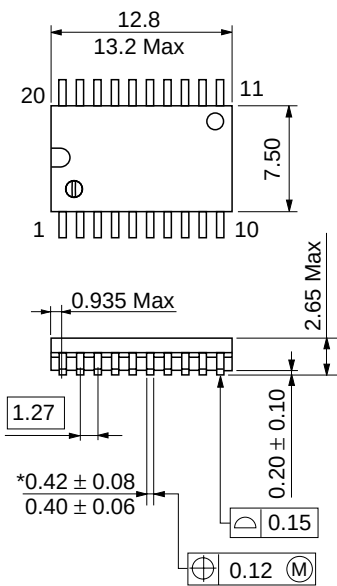


*Dimension including the plating thickness
Base material dimension

Hitachi Code	FP-20DA
JEDEC	—
EIAJ	Conforms
Mass (reference value)	0.31 g

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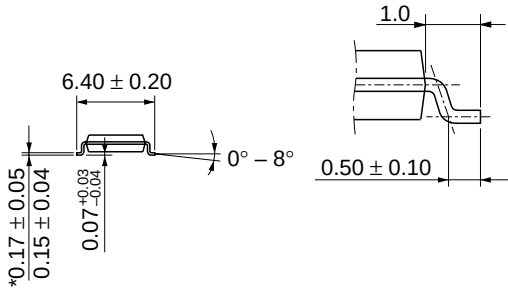
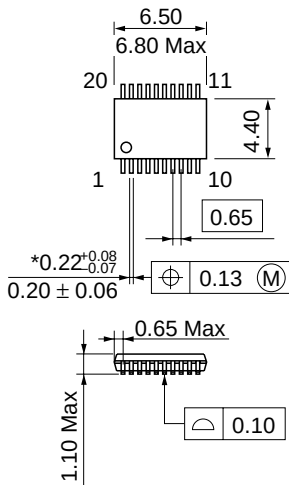
Unit: mm



*Dimension including the plating thickness
Base material dimension

Hitachi Code	FP-20DB
JEDEC	Conforms
EIAJ	—
Mass (reference value)	0.52 g

Unit: mm



*Dimension including the plating thickness
Base material dimension

Hitachi Code	TTP-20DA
JEDEC	—
EIAJ	—
Mass (reference value)	0.07 g

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HITACHI

Hitachi, Ltd.

Semiconductor & Integrated Circuits.
Nippon Bldg., 2-6-2, Ohite-machi, Chiyoda-ku, Tokyo 100-0004, Japan
Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109

URL	North America	: http://semiconductor.hitachi.com/
	Europe	: http://www.hitachi-eu.com/hel/ecg
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For further information write to:

Hitachi Semiconductor
(America) Inc.
179 East Tasman Drive,
San Jose, CA 95134
Tel: <1> (408) 433-1990
Fax: <1> (408) 433-0223

Hitachi Europe GmbH
Electronic Components Group
Dornacher Straße 3
D-85622 Feldkirchen, Munich
Germany
Tel: <49> (89) 9 9180-0
Fax: <49> (89) 9 29 30 00

Hitachi Europe Ltd.
Electronic Components Group.
Whitebrook Park
Lower Cookham Road
Maidenhead
Berkshire SL6 8YA, United Kingdom
Tel: <44> (1628) 585000
Fax: <44> (1628) 585160

Hitachi Asia Ltd.
Hitachi Tower
16 Collyer Quay #20-00,
Singapore 049318
Tel: <65>-538-6533/538-8577
Fax: <65>-538-6933/538-3877
URL: <http://www.hitachi.com.sg>

Hitachi Asia Ltd.
(Taipei Branch Office)
4/F, No. 167, Tun Hwa North Road,
Hung-Kuo Building,
Taipei (105), Taiwan
Tel: <886>-(2)-2718-3666
Fax: <886>-(2)-2718-8180
Telex: 23222 HAS-TP
URL: <http://www.hitachi.com.tw>

Hitachi Asia (Hong Kong) Ltd.
Group III (Electronic Components)
7/F., North Tower,
World Finance Centre,
Harbour City, Canton Road
Tsim Sha Tsui, Kowloon,
Hong Kong
Tel: <852>-(2)-735-9218
Fax: <852>-(2)-730-0281
URL: <http://www.hitachi.com.hk>

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